Analog Devices Inc./Maxim Integrated - MAX32620IWG+T Datasheet

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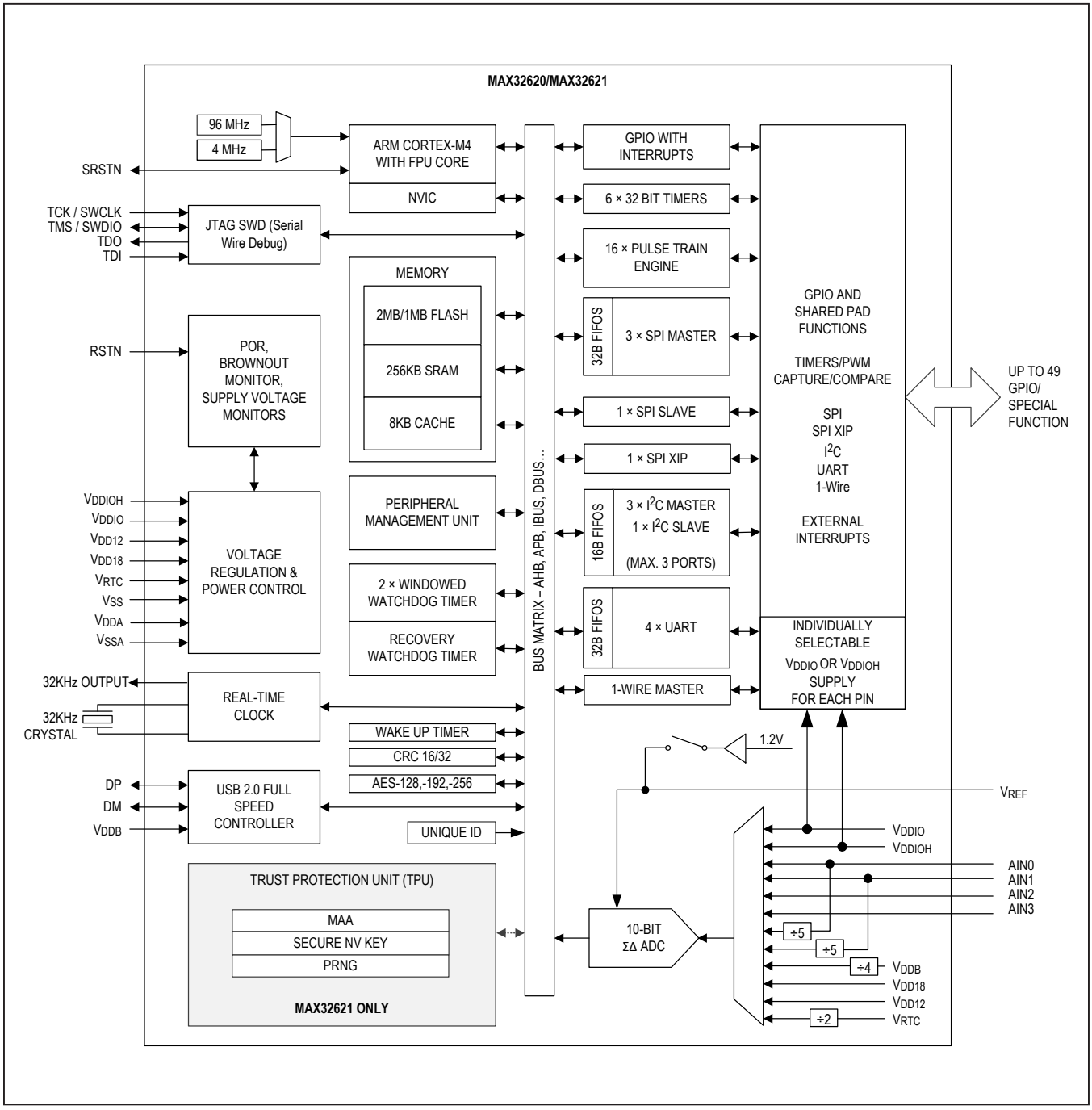
Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M4F
Core Size	32-Bit Single-Core
Speed	96MHz
Connectivity	1-Wire, I²C, SPI, UART/USART, USB
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	49
Program Memory Size	2MB (2M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	256K x 8
Voltage - Supply (Vcc/Vdd)	1.14V ~ 3.6V
Data Converters	A/D 4x10b
Oscillator Type	Internal
Operating Temperature	-30°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	81-WFBGA, WLBGA
Supplier Device Package	81-WLP (3.95x4.11)
Purchase URL	https://www.e-xfl.com/product-detail/analog-devices/max32620iwg-t

MAX32620/MAX32621 Block Diagram



Absolute Maximum Ratings

(All voltages with respect to V_{SS}, unless otherwise noted.)

V_{DD18} .....-0.3V to +1.89V
V_{DD12} .....-0.3V to +1.26V
V_{DDA} with respect to V_{SSA} .....-0.3V to +1.89V
V_{RTC}.....-0.3V to +1.89V
V_{DDB} .....-0.3V to +3.6V
V_{REF}.....-0.3V to +3.6V
32KIN, 32KOUT.....-0.3V to +3.6V
RSTN, SRSTN, GPIO, DP, DM, JTAG .....-0.3V to +3.6V
AIN[1:0].....-0.3V to +5.5V
AIN[3:2].....-0.3V to +3.6V
V_{DDIO} .....-0.3V to +3.6V
V_{DDIOH}.....-0.3V to +3.6V
Total current V_{DD18}, V_{DDIO}(sink).....100mA
Total current V_{SS}.....100mA
Output current (sink) by Any I/O pin..... 25mA
Output current (source) by Any I/O pin .....-25mA
Continuous Power Dissipation (T_A = +70°C)
TQFP (multilayer board)
(derate 45.5mW/°C above +70°C) 3636.4mW
Operating Temperature Range..... -30°C to +85°C
Storage Temperature Range..... -65°C to +150°C
Soldering Temperature (reflow).....+260°C

This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

Package Thermal Characteristics (Note 1)

TQFP
Junction-to-Ambient Thermal Resistance (θ_{JA}) .....22°C/W
Junction-to-Case Thermal Resistance (θ_{JC}).....2°C/W

WLP
Junction-to-Ambient Thermal Resistance (θ_{JA}) .....36°C/W

Note 1: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to **www.maximintegrated.com/thermal-tutorial**.

Electrical Characteristics

(Limits are tested at T_A = +25°C and T_A = +85°C. Limits over the operating temperature range and relevant supply voltage range are guaranteed by design and characterization. Specifications marked GBD are guaranteed by design and not production tested.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage	V_{DD18}		1.71	1.8	1.89	V
	V_{DD12}		1.14	1.2	1.26	
	V_{DDA}		1.71	1.8	1.89	
	V_{RTC}		1.71	1.8	1.89	
	V_{DDB}		3.04	3.3	3.60	
	V_{DDIO}		1.71	1.8	3.60	
	V_{DDIOH}	V_{DDIOH} must be ≥ V_{DDIO}	1.71	1.8	3.60	
Power-Fail Reset Voltage	V_{RST}	Monitors V_{DD18}	1.1		1.70	V
Power On Reset Voltage	V_{POR}	Monitors V_{DD18}		1.5		V
RAM Data Retention Voltage	V_{DRV}	V_{DD12} supply, retention in LP1		0.93		V
V_{DD12} Dynamic Current, LP3 Mode	I_{DD12_DLP3}	Measured on the V_{DD12} pin and executing code from cache memory, all inputs are tied to V_{SS} or V_{DDIO}, outputs do not source/sink any current, PMU disabled		102		µA/MHz

Electrical Characteristics (continued)

(Limits are tested at T_A = +25°C and T_A = +85°C. Limits over the operating temperature range and relevant supply voltage range are guaranteed by design and characterization. Specifications marked GBD are guaranteed by design and not production tested.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
V_{DD12} Current, LP3 Mode	I_{DD12_LP3}	96MHz oscillator selected as system clock, measured on the V_{DD12} pin and executing code from cache memory, all inputs are tied to V_{SS} or V_{DDIO}, outputs do not source/sink any current		96		µA
		4MHz oscillator selected as system clock measured on the V_{DD12} pin and executing code from cache memory, all inputs are tied to V_{SS} or V_{DDIO}, outputs do not source/sink any current		49		
V_{DD18} Current, LP3 Mode	I_{DD18_LP3}	96MHz oscillator selected as system clock, measured on the V_{DD18} pin and executing code from cache memory, all inputs are tied to V_{SS} or V_{DDIO}, outputs do not source/sink any current		366		µA
		4MHz oscillator selected as system clock, measured on the VDD18 pin and executing code from cache memory, all inputs are tied to V_{SS} or V_{DDIO}, outputs do not source/sink any current.		33		
V_{RTC} Current, LP3 Mode	I_{RTC_LP3}	RTC disabled		1.15		µA
		RTC enabled		1.55		µA
V_{DD12} Dynamic Current, LP2 Mode	I_{DD12_DLP2}	Measured on the V_{DD12} pin, ARM in sleep mode, PMU with two channels active		23		µA/ MHz
V_{DD12} Current, LP2 Mode	I_{DD12_LP2}	96MHz oscillator selected as system clock, measured on the V_{DD12} pin, ARM in sleep mode, system clock stopped		96		µA
		4MHz oscillator selected as system clock, measured on the V_{DD12} pin, ARM in sleep mode, system clock stopped		49		
V_{DD18} Current, LP2 Mode	I_{DD18_LP2}	96MHz oscillator selected as system clock, ARM in sleep mode, PMU with two channels active, all inputs are tied to V_{SS} or V_{DDIO}, outputs do not source/sink any current		366		µA
		4MHz oscillator selected as system clock, ARM in sleep mode, PMU with two channels active, all inputs are tied to V_{SS} or V_{DDIO}, outputs do not source/sink any current		33		
V_{RTC} Current, LP2 Mode	I_{RTC_LP2}	RTC disabled		1.15		µA
		RTC enabled		1.55		µA

Electrical Characteristics (continued)

(Limits are tested at T_A = +25°C and T_A = +85°C. Limits over the operating temperature range and relevant supply voltage range are guaranteed by design and characterization. Specifications marked GBD are guaranteed by design and not production tested.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Input High Voltage for $\overline{SRSTN}$, and All Port Pins	V_{IH}	Legacy V_{DD18} I/O supply, includes JTAG	0.7 x V_{DD18}			V
		V_{DDIO} selected as I/O supply, includes JTAG	0.7 x V_{DDIO}			
		V_{DDIOH} selected as I/O supply	0.7 x V_{DDIOH}			
Input High Voltage for $\overline{RSTN}$	V_{IH}	Legacy V_{DD18} I/O supply	0.7 x V_{RTC}			V
		V_{DDIO} or V_{DDIOH} selected as I/O supply	0.7 x V_{RTC}			
Input Hysteresis (Schmitt)	V_{IHYS}			100		mV
Output Low Voltage for All Port Pins	V_{OL}	I_{OL} = 4mA (normal drive), legacy V_{DD18} I/O supply, includes JTAG		0.2	0.4	V
		I_{OL} = 24mA (high drive), legacy V_{DD18} I/O supply, includes JTAG		0.2	0.4	
		I_{OL} = 4mA (normal drive), V_{DDIO} = V_{DDIOH} = 1.71V, V_{DDIO} selected as I/O supply, includes JTAG		0.2	0.4	
		I_{OL} = 24mA (high drive), V_{DDIO} = V_{DDIOH} = 1.71V, V_{DDIO} selected as I/O supply		0.2	0.4	
		I_{OL} = 900µA, V_{DDIO} = 1.71V, V_{DDIOH} = 2.97V, V_{DDIOH} selected as I/O supply		0.2	0.45	
Combined I_{OL}, All GPIO	I_{OL_TOTAL}				48	mA
Output High Voltage for All Port Pins	V_{OH}	I_{OH} = -2mA (normal drive), legacy V_{DD18} I/O supply, includes JTAG	V_{DD18} - 0.4			V
		I_{OH} = -8mA (high drive), legacy V_{DD18} I/O supply, includes JTAG	V_{DD18} - 0.4			
		I_{OH} = -2mA (normal drive), V_{DDIO} = V_{DDIOH} = 1.7V, V_{DDIO} selected as I/O supply, includes JTAG	V_{DDIO} - 0.4			
		I_{OH} = -8mA (high drive), V_{DDIO} = V_{DDIOH} = 1.7V, V_{DDIO} selected as I/O supply, includes JTAG	V_{DDIO} - 0.4			
		I_{OH} = -300µA, V_{DDIOH} = 2.97V, V_{DDIOH} selected as I/O supply	V_{DDIO} - 0.4			
		I_{OH} = -2mA, V_{DDIO} = 1.71V, V_{DDIOH} = 2.97V, V_{DDIO} selected as I/O supply	V_{DDIO} - 0.45			

Electrical Characteristics (continued)

(Limits are tested at T_A = +25°C and T_A = +85°C. Limits over the operating temperature range and relevant supply voltage range are guaranteed by design and characterization. Specifications marked GBD are guaranteed by design and not production tested.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Combined I_{OH}, All GPIO	I_{OH_TOTAL}				48	mA
Input/Output Pin Capacitance for All Port Pins	C_{IO}			3		pF
Input Leakage Current Low	I_{IL}	V_{DD18} = 1.89V V_{IN} = 0V, internal pullup disabled, legacy V_{DD18} I/O supply	-100		+100	nA
		V_{DDIO} = 1.89V, V_{DDIOH} = 3.6V, V_{DDIOH} selected as I/O supply, V_{IN} = 0V, internal pullup disabled	-100		+100	
Input Leakage Current High	I_{IH}	V_{DD18} = 1.89V, V_{IN} = 1.89V, internal pulldown disabled, legacy V_{DD18} I/O supply	-100		+100	nA
		V_{DDIO} = 1.89V, V_{DDIOH} = 3.6V, V_{IN} = 3.6V, internal pulldown disabled, V_{DDIOH} selected as I/O supply	-100		+100	
	I_{OFF}	V_{DD18} = 0V, V_{IN} < 1.89V, legacy V_{DD18} I/O supply	-1		+1	µA
		V_{DDIO} = 0V, V_{DDIOH} = 0V, V_{DDIO} selected as I/O supply, V_{IN} < 1.89V	-1		+1	
	I_{IH3V}	V_{DD18} = 1.71V, V_{IN} = 3.60V, legacy V_{DD18} I/O supply	-2		+2	µA
		V_{DDIO} = V_{DDIOH} = 1.71V, V_{DDIO} selected as I/O supply, V_{IN} =3.6V	-2		+2	
Input Pullup Resistor, $\overline{SRSTN}$, TMS, TCK, TDI	R_{PU_VDDIO}	Pullup to V_{DDIO}		25		kΩ
Input Pullup Resistor $\overline{RSTN}$	R_{PU_VRTC}	Pullup to V_{RTC}		25		kΩ
Input Pullup/Pulldown All GPIO	R_{PU_GPIO}	Normal resistance mode		25		kΩ
		Highest resistance mode		1		MΩ
FLASH MEMORY						
Page Size				8		kB
Flash Erase Time	t_{M_ERASE}	Mass erase		30		ms
	t_{P_ERASE}	Page erase		30		ms
Flash Programming Time Per Word	t_{PROG}			60		µs
Flash Endurance			10			kcycles
Data Retention	t_{RET}	T_A = +85°C	10			years

ADC Electrical Characteristics (continued)

(Limits are tested at T_A = +25°C and T_A = +85°C. Limits over the operating temperature range and relevant supply voltage range are guaranteed by design and characterization. Specifications marked GBD are guaranteed by design and not production tested.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Input Impedance	R_{AIN}	AIN[1:0], ADC_HSEL = 4–5, ADC active		45		kΩ
Input Dynamic Current, Switched Capacitance	I_{AIN}	ADC active, ADC buffer bypassed		4.5		µA
		ADC active, ADC buffer enabled		50		nA
Analog Input Capacitance	C_{AIN}	Fixed capacitance to ground		1		pF
		Dynamically switched capacitance		250		nF
Integral Nonlinearity	INL				±2	LSb
Differential Nonlinearity	DNL				±1	LSb
Offset Error	V_{OS}			±1		LSb
Gain Error	GE			±2		LSb
ADC Active Current	I_{ADC}	ADC active, reference buffer enabled, input buffer disabled		240		µA
Input Buffer Active Current	I_{INBUF}			53		µA
ADC Setup Time	t_{ADC_SU}	Any power-up of: ADC clock, ADC bias, reference buffer, or input buffer to CpuAdcStart			10	µs
		Any power-up of: ADC clock or ADC bias to CpuAdcStart			48	t_{ACLK}
ADC Output Latency	t_{ADC}			1025		t_{ACLK}
ADC Sample Rate	f_{ADC}				7.80	ksps
ADC Input Leakage	I_{ADC_LEAK}	AIN0 or AIN1, ADC inactive or channel not selected		0.12	4	nA
		AIN2 or AIN3, ADC inactive or channel not selected		0.02	1.0	nA
AIN0/AIN1 Resistor Divider Error		ADC_CHSEL = 4 or 5, not including ADC offset/gain error		±2		LSb
Full-Scale Voltage	V_{FS}	ADC code = 0x3FF		1.20		V
Signal to Noise Ratio	SNR			58.5		dB
Signal to Noise and Distortion	SINAD			58.5		dB
Total Harmonic Distortion	THD			-68.5		dB
Spurious Free Dynamic Range	SFDR			74		dB
Bandgap Temperature Coefficient	V_{TEMPCO}	Box method		30		ppm/°C
Reference Input Capacitance	C_{REF_IN}	Dynamically switched capacitance, ADC_XREF=1, ADC active		250		fF
External Reference Voltage	V_{REF_EXT}	ADC_XREF = 1	1.17	1.23	1.29	V
Reference Dynamic Current	I_{REF_EXT}	ADC_XREF=1, ADC active		4.1		µA

Electrical Characteristics—SPI Master/SPIX Master

(Timing specifications are guaranteed by design and are not production tested.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Master Operating Frequency	f_{MCK}				48	MHz
Master SCLK Period	t_{MCK}			$1/f_{MCK}$		ns
SCLK Output Pulse-Width High	t_{MCH}		$t_{MCK}/2$			ns
SCLK Output Pulse-Width Low	t_{MCL}		$(t_{MCK}/2) - 4$			ns
MOSI Output Hold Time After SCLK Sample Edge	t_{MOH}		$(t_{MCK}/2) - 4$			ns
MOSI Output Valid to Sample Edge	t_{MOV}		$(t_{MCK}/2) - 4$			ns
MISO Input Valid to SCLK Sample Edge Setup	t_{MIS}		1			ns
MISO Input to SCLK Sample Edge	t_{MIH}				1	ns

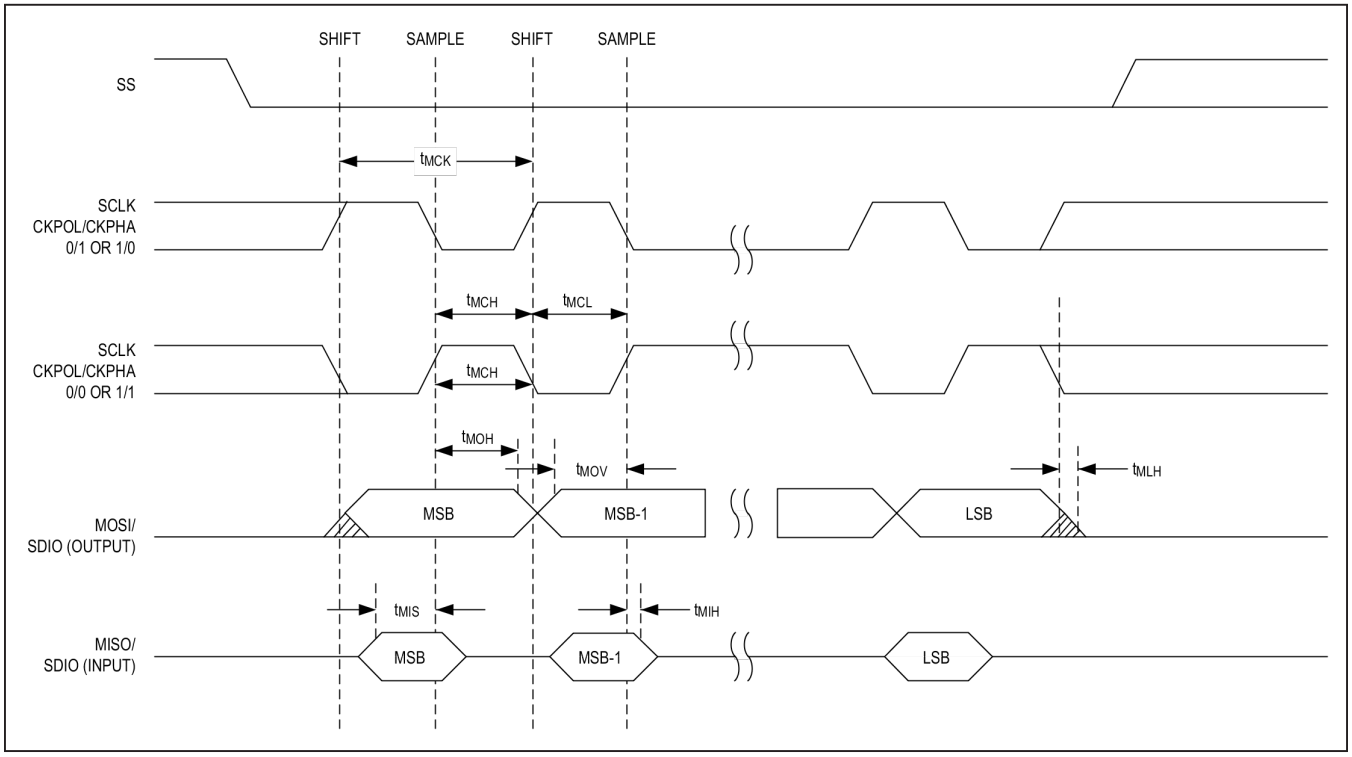


Figure 1. SPI Master and SPI XIP Master Timing

Electrical Characteristics—SPI Slave

(Timing specifications are guaranteed by design and are not production tested.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Slave Operating Frequency, Write	f_{SCK_W}	Standard SPI mode			48	MHz
		Fast SPI mode			48	
Slave Operating Frequency	f_{SCK_R}	Standard SPI mode			22.7	MHz
		Fast SPI mode			45.5	
SCLK Period	t_{SCK}			$1/f_{SCK}$		ns

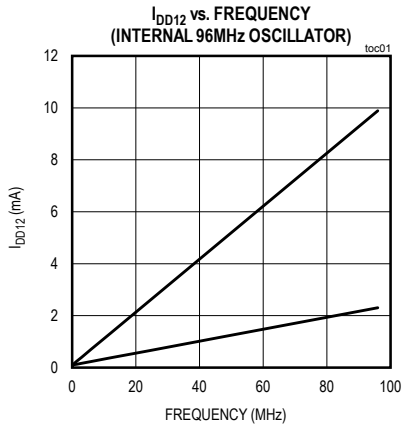
Electrical Characteristics—I²C Bus

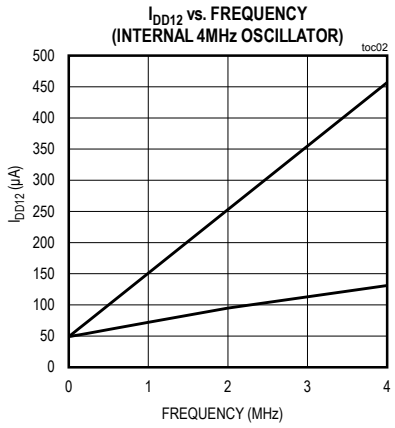
(Limits are 100% tested at T_A = +25°C and T_A = +85°C. Limits over the operating temperature range and relevant supply voltage range are guaranteed by design and characterization. Specifications marked "GBD" are guaranteed by design and not production tested.)

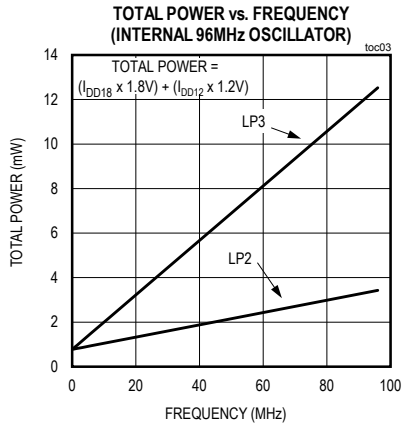
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
I²C BUS						
Input High Voltage	V_{IH_I2C}	Standard mode, V_{DDIO} selected as I/O supply	0.7 × V_{DDIO}			V
		Standard mode, V_{DDIOH} selected as I/O supply	0.7 × V_{DDIOH}			
		Fast mode, V_{DDIO} selected as I/O supply	0.7 × V_{DDIO}		V_{DDIO} + 0.5	
		Fast mode, V_{DDIOH} selected as I/O supply	0.7 × V_{DDIOH}		V_{DDIOH} + 0.5	
Input Low Voltage	V_{IL_I2C}	Standard mode, V_{DDIO} selected as I/O supply	-0.5		0.3 × V_{DDIO}	V
		Standard mode, V_{DDIOH} selected as I/O supply	-0.5		0.3 × V_{DDIOH}	
		Fast mode, V_{DDIO} selected as I/O supply	-0.5		0.3 × V_{DDIO}	
		Fast mode, V_{DDIOH} selected as I/O supply	-0.5		0.3 × V_{DDIOH}	
Input Hysteresis (Schmitt)	V_{IHYS_I2C}	Fast mode, V_{DDIO} selected as I/O supply	0.05 x V_{DDIO}			V
		Fast mode, V_{DDIOH} selected as I/O supply	0.05 x V_{DDIOH}			
Output Logic-Low (Open Drain or Open Collector)	V_{OL_I2C}	Standard mode, I_{IL} = 3mA	0		0.4	V
		Fast mode, I_{IL} = 3mA	0		0.4	
		Fast mode, I_{IL} = 2mA, V_{DDIO} selected as I/O supply	0		0.2 x V_{DDIO}	
		Fast mode, I_{IL} = 2mA, V_{DDIOH} selected as I/O supply	0		0.2 x V_{DDIOH}	
I²C TIMING						
SCL Clock Frequency	f_{SCL}	Standard mode	0		100	kHz
		Fast mode	0		400	

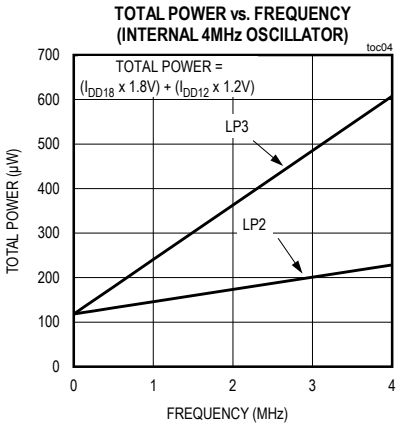
Typical Operating Characteristics

(V_{DD18} = 1.8V, V_{DD18} = 1.8V.)

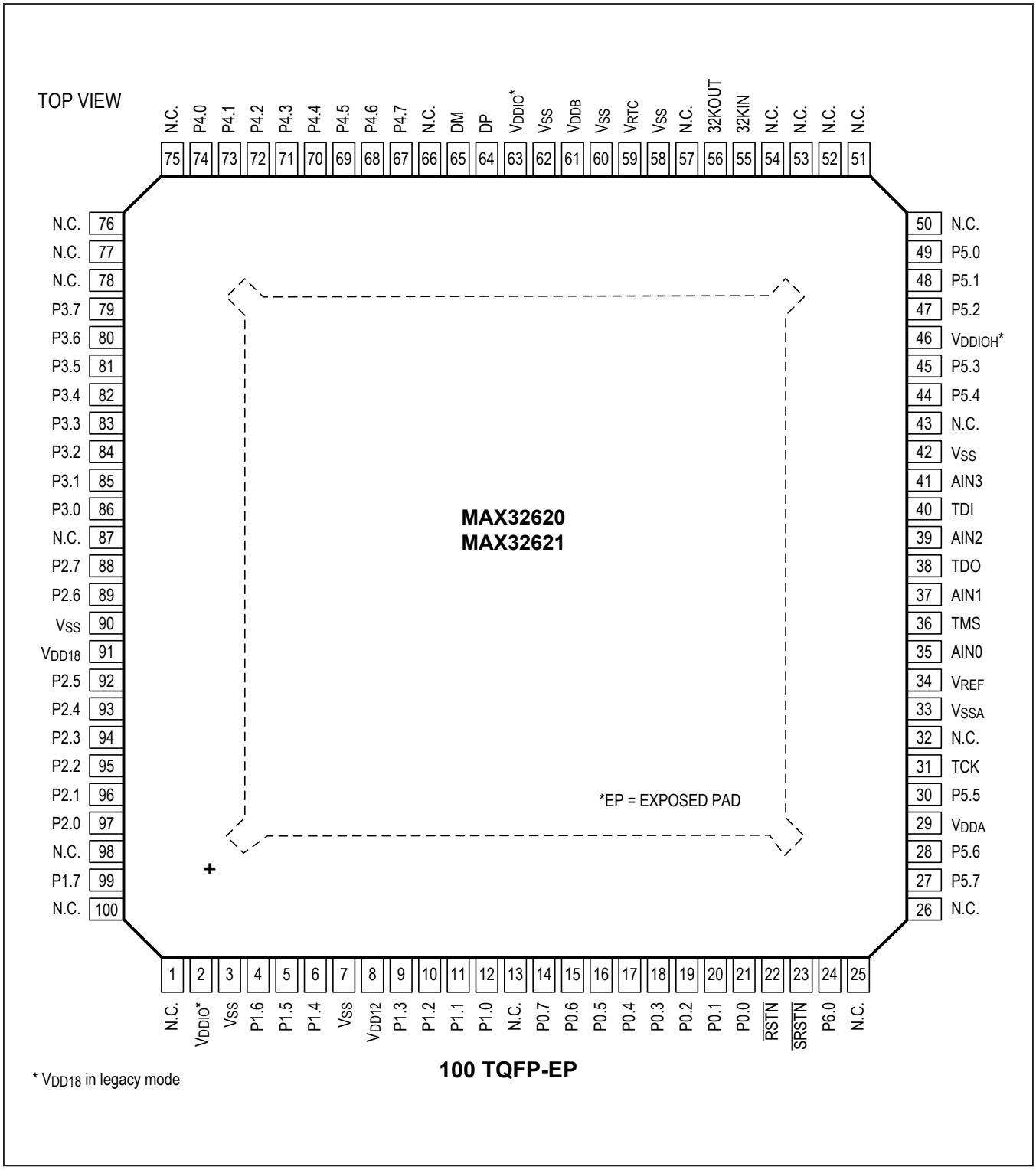








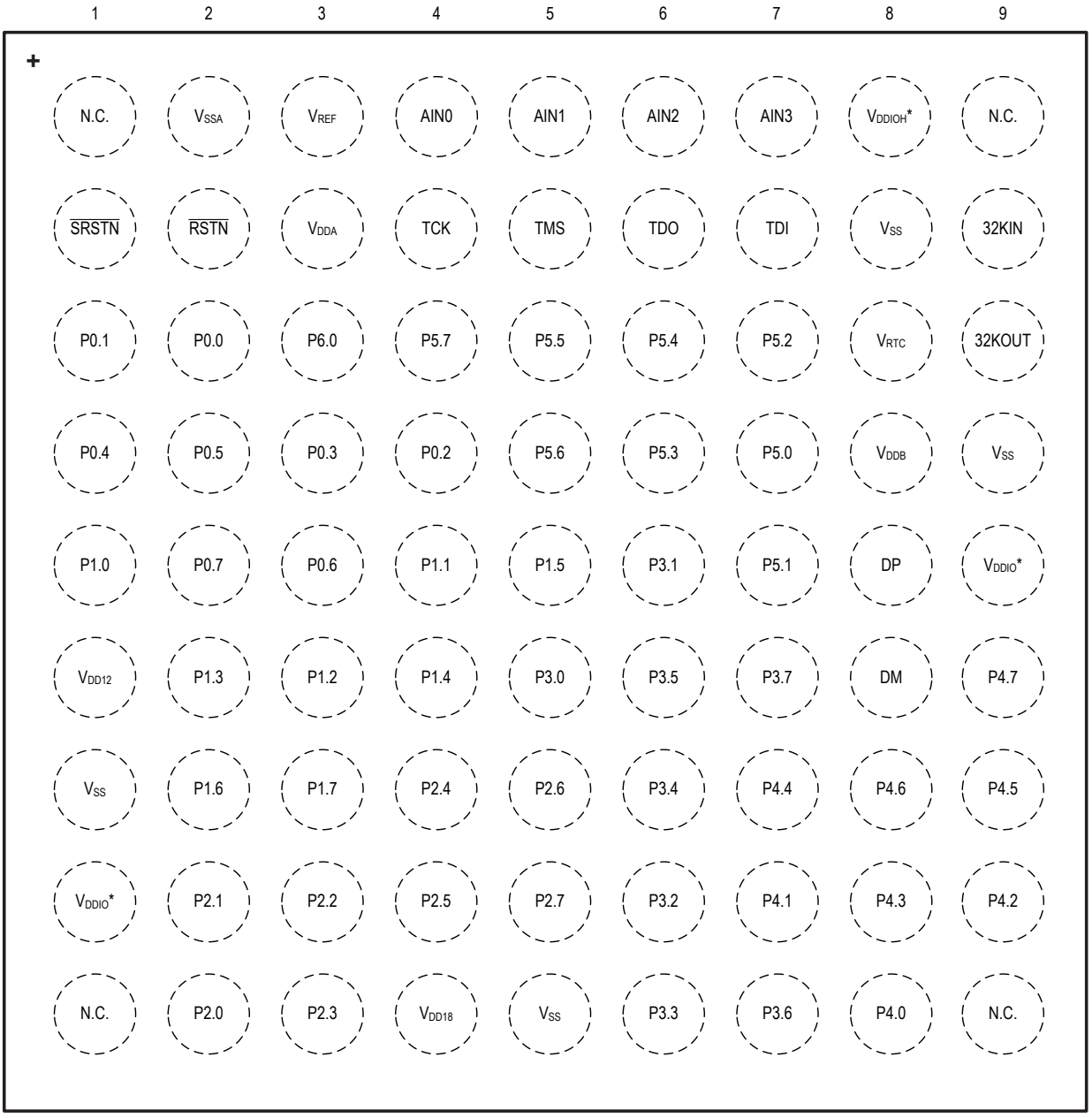
Pin Configuration



Pin Configuration (continued)

TOP VIEW (BUMP SIDE DOWN)

MAX32620
MAX32621



100 WLP

* V_{DD18} in legacy mode

Pin Description

PIN		NAME	FUNCTION
TQFP	WLP		
POWER			
61	D8	V_{DDB}	USB Transceiver Supply Voltage. This pin must be bypassed to V_{SS} with a 1.0µF capacitor as close as possible to this pin.
8	F1	V_{DD12}	1.2V Supply Voltage. This pin must be bypassed to V_{SS} with a 1.0µF capacitor as close as possible to this pin.
59	C8	V_{RTC}	RTC Supply Voltage. This pin must be bypassed to V_{SS} with a 1.0µF capacitor as close as possible to this pin.
29	B3	V_{DDA}	Analog Supply Voltage. This pin must be bypassed to V_{SSA} with a 1.0µF capacitor as close as possible to this pin.
91	J4	V_{DD18}	1.8V Supply Voltage. This pin must be bypassed to V_{SS} with a 1.0µF capacitor as close as possible to this pin.
2, 63	E9, H1	V_{DDIO}	I/O Supply Voltage. 1.8V ≤ V_{DDIO} ≤ 3.6V. See EC table for V_{DDIO} specification. This pin must be bypassed to V_{SS} with a 1.0µF capacitor as close as possible to the package. This pin can be connected to V_{DD18} for legacy I/O support.
46	A8	V_{DDIOH}	I/O Supply Voltage, High. 1.8V ≤ V_{DDIOH} ≤ 3.6V, always with V_{DDIO} ≤ V_{DDIOH}. See EC table for V_{DDIOH} specification. This pin must be bypassed to V_{SS} with a 1.0µF capacitor as close as possible to the package. This pin can be connected to V_{DD18} for legacy I/O support.
34	A3	V_{REF}	ADC Reference. This pin should be left unconnected if an external reference is not used.
3, 7, 42, 58, 60, 62, 90	B8, D9, G1, J5	V_{SS}	Digital Ground.
33	A2	V_{SSA}	Analog Ground. This pin must be connected to V_{SS}.
EP	—	EP	Exposed Pad (TQFP Only). This pad must be connected to V_{SS}. Refer to Application Note 3273: Exposed Pads: A Brief Introduction for additional information.
CLOCKS			
55	B9	32KIN	32kHz Crystal Oscillator Input/Output. Connect a 6pF 32kHz crystal between 32KIN and 32KOUT for RTC operation. Optionally, an external clock source can be driven on 32KIN if the 32KOUT pin is left unconnected. A 32kHz crystal or external clock source is required for proper USB operation.
56	C9	32KOUT	
USB			
64	E8	DP	USB D+ Signal. This bidirectional pin carries the positive differential data or single-ended data. This pin is weakly pulled high internally when the USB is disabled.
65	F8	DM	USB D- Signal. This bidirectional pin carries the negative differential data or single-ended data. This pin is weakly pulled high internally when the USB is disabled.
JTAG			
31	B4	TCK	JTAG Clock Serial Wire Debug Clock This pin has an internal 25kΩ pullup to V_{DDIO}.

Table 1. MAX32620/MAX32621 GPIO Special Function Cross Reference (continued)

GPIO	SPECIAL FUNCTIONS						
P2.2	UART1A_CTS	UART1B_RTS	PT_PT2	TIMER_TMR0	GPIO_INT(P2)		
P2.3	UART1A_RTS	UART1B_CTS	PT_PT3	TIMER_TMR1	GPIO_INT(P2)		
P2.4	SPIM2A_SCK		PT_PT4	TIMER_TMR2	GPIO_INT(P2)		
P2.5	SPIM2A_MOSI/ SDIO0		PT_PT5	TIMER_TMR3	GPIO_INT(P2)		
P2.6	SPIM2A_MISO/ SDIO1		PT_PT6	TIMER_TMR4	GPIO_INT(P2)		
P2.7	SPIM2A_SS0		PT_PT7	TIMER_TMR5	GPIO_INT(P2)		
P3.0	UART2A_RX	UART2B_TX	PT_PT8	TIMER_TMR0	GPIO_INT(P3)		
P3.1	UART2A_TX	UART2B_RX	PT_PT9	TIMER_TMR1	GPIO_INT(P3)		
P3.2	UART2A_CTS	UART2B_RTS	PT_PT10	TIMER_TMR2	GPIO_INT(P3)		
P3.3	UART2A_RTS	UART2B_CTS	PT_PT11	TIMER_TMR3	GPIO_INT(P3)		
P3.4	I2CM1/SB_SDA	SPIM2A_SS1	PT_PT12	TIMER_TMR4	GPIO_INT(P3)		
P3.5	I2CM1/SB_SCL	SPIM2A_SS2	PT_PT13	TIMER_TMR5	GPIO_INT(P3)		
P3.6	SPIM1_SS1	SPIX_SS1	PT_PT14	TIMER_TMR0	GPIO_INT(P3)		
P3.7	SPIM1_SS2	SPIX_SS2	PT_PT15	TIMER_TMR1	GPIO_INT(P3)		
P4.0	OWM_I/O	SPIM2A_SR0	PT_PT0	TIMER_TMR2	GPIO_INT(P4)		
P4.1	OWM_PUPEN	SPIM2A_SR1	PT_PT1	TIMER_TMR3	GPIO_INT(P4)		
P4.2	SPIM0_SDIO2		PT_PT2	TIMER_TMR4	GPIO_INT(P4)		
P4.3	SPIM0_SDIO3		PT_PT3	TIMER_TMR5	GPIO_INT(P4)		
P4.4	SPIM0_SS1		PT_PT4	TIMER_TMR0	GPIO_INT(P4)		
P4.5	SPIM0_SS2		PT_PT5	TIMER_TMR1	GPIO_INT(P4)		
P4.6	SPIM0_SS3		PT_PT6	TIMER_TMR2	GPIO_INT(P4)		
P4.7	SPIM0_SS4		PT_PT7	TIMER_TMR3	GPIO_INT(P4)		
P5.0	Reserved	SPIM2B_SCK	PT_PT8	TIMER_TMR4	GPIO_INT(P5)		
P5.1	Reserved	SPIM2B_ MOSI/SDIO0	PT_PT9	TIMER_TMR5	GPIO_INT(P5)		
P5.2	Reserved	SPIM2B_ MISO/SDIO1	PT_PT10	TIMER_TMR0	GPIO_INT(P5)		
P5.3	Reserved	SPIM2B_SS0	PT_PT11	TIMER_TMR1	GPIO_INT(P5)	UART3A_RX	UART3B_TX
P5.4	Reserved	SPIM2B_ SDIO2	PT_PT12	TIMER_TMR2	GPIO_INT(P5)	UART3A_TX	UART3B_RX
P5.5	Reserved	SPIM2B_ SDIO3	PT_PT13	TIMER_TMR3	GPIO_INT(P5)	UART3A_CTS	UART3B_RTS
P5.6	Reserved	SPIM2B_SR	PT_PT14	TIMER_TMR4	GPIO_INT(P5)	UART3A_RTS	UART3B_CTS
P5.7	I2CM2/SC_SDA	SPIM2B_SS1	PT_PT15	TIMER_TMR5	GPIO_INT(P5)		
P6.0	I2CM2/SC_SCL	SPIM2B_SS2	PT_PT0	TIMER_TMR0	GPIO_INT(P5)		

MAX32620/MAX32621 Detailed Description

The MAX32620/MAX32621 is a low-power, mixed signal microcontroller that includes the ARM Cortex-M4 with FPU core with a maximum operating frequency of 96MHz. An internal 4MHz oscillator supports minimal power consumption for applications requiring always-on monitoring. The MAX32621 is a secure version, incorporating a trust protection unit (TPU) with encryption and advanced security features.

Application code executes from an onboard 2MB/1MB program flash memory, with 256KB SRAM available for general application use. An 8KB instruction cache improves execution throughput, and a transparent code scrambling scheme protects customer intellectual property residing in the program flash memory. Additionally, a SPI execute in place (SPIX) external memory interface allows application code and data (up to 16MB) to be accessed from an external SPI memory device.

A 10-bit sigma-delta ADC is provided with a multiplexer front end for four external input channels (two of which are 5.5V tolerant) and internal channels to monitor supply voltages. Built-in limit monitors allow converted input samples to be compared against user-configurable high and low limits, with an option to trigger an interrupt and wake the CPU from a low power mode if attention is required.

A wide variety of communications and interface peripherals are provided, including a USB 2.0-compliant slave interface, three master SPI interfaces, four UART interfaces with multidrop support, three master I^2C interfaces, and a slave I^2C interface.

ARM Cortex-M4 with FPU Core

The ARM Cortex-M4 with FPU core is ideal for the emerging category of wearable medical and wellness applications. The architecture combines high-efficiency signal processing functionality with low power, low cost, and ease of use.

- Floating Point Unit (FPU)
- Memory Protection Unit
- Full debug support level
  - Debug Access Port (DAP)
  - Breakpoints
  - DWT
  - Flash patch
  - Halting debug
- Debug access port : JTAG or serial wire
- NVIC support
  - 52 interrupts to be grouped by firmware into 8 levels of priority
- DSP supports Single Instruction Multiple Data (SIMD) Path DSP extensions, providing:
  - 4 parallel 8 bit add/sub
  - 2 parallel 16 bit add/sub
  - 2 parallel MACs
  - 32 or 64 bit accumulate
  - Signed, unsigned, data with or without saturation

Power Operating Modes

Low Power Mode 0 (LP0)

This mode places the core and peripheral logic in a static, low-power state. All features of the device are disabled except:

- Power sequencer
- RTC (if enabled)
- Key data retention registers
- Power-on reset
- Voltage supply monitoring

Data retention in this mode can be maintained using only the V_{RTC} supply, with all other voltage supplies disabled.

Low Power Mode 1 (LP1)

This mode places the core logic in a static, low-power state which supports a fast wakeup feature. Data retention in this mode can be maintained using only the V_{RTC} supply, with all other voltage supplies disabled.

Low Power Mode 2 (LP2)

This configuration allows the ADC and some peripherals to operate while the ARM core is in sleep mode. The peripheral management unit provides intelligent, dynamic clocking of any enabled peripherals, ensuring the lowest power consumption possible.

Low Power Mode 3 (LP3)

During this state, the CPU is executing application code and all digital and analog peripherals are fully powered and awake. Dynamic clocking disables peripherals not in use, providing the optimal mix of high-performance and low power consumption.

Analog to Digital Converter (ADC)

The 10-bit sigma-delta ADC provides 4 external inputs and can also be configured to measure all internal power supplies. It operates at a maximum of 7.8ksps. AIN0 and AIN1 are 5.5V tolerant, making them suitable for monitoring batteries.

An optional feature allows samples captured by the ADC to be automatically compared against user-programmable high and low limits. Up to four channel limit pairs can be configured in this way. The comparison allows the ADC to trigger an interrupt (and potentially wake the CPU from a low power sleep mode) when a captured sample goes outside the preprogrammed limit range. Since this comparison is performed directly by the sample limit monitors, it can be performed even while the main CPU is suspended in a low-power mode.

The ADC reference can be the internal 1.2V bandgap or an external reference.

The ADC measures:

- AIN[3:2] (up to 3.3V)
- AIN[1:0] (up to 5.5V)
- V_{DD12}
- V_{DD18}
- V_{DDB}
- V_{RTC}
- V_{DDIO}
- V_{DDIOH}

Pulse Train Engine

Sixteen independent pulse train generators provide either a square wave or a repeating pattern from 2 bits to 32 bits in length.

Each pulse train generator is independently configurable. The pulse train generators provide the following:

- Independently enabled
- Multiple pin configurations allow for flexible layout
- Pulse trains can be started/synchronized independently or as a group
- Frequency of each enabled pulse train generator is also set separately, based on a divide down (divide by 2, divide by 4, divide by 8, and so on) of the input pulse train module clock
- Multiple repetition options for pulse train mode
  - Single shot (nonrepeating pattern of 2-32 bits)
  - Pattern repeats user-configurable number of times or indefinitely
  - End of one pulse train's loop count can restart one or more other pulse trains

Clocking Scheme

The high-frequency internal relaxation oscillator operates at a nominal frequency of 96MHz. It is the primary clock source for the digital logic and peripherals. The 4MHz internal oscillator can be selected to optimize active power consumption. Wakeup is possible from either the 4MHz or the 96MHz internal oscillator.

An external 32.768kHz timebase is required when using the RTC or USB features of the device. The time base can be generated by attaching a 32kHz crystal. An external clock source can also be applied to the 32KIN pin. The external clock source must meet the electrical/timing requirements in the EC table.

Interrupt Sources

The ARM nested vector interrupt controller (NVIC) provides high speed, deterministic interrupt response, interrupt masking, and multiple interrupt sources. Each peripheral is connected to the NVIC and can have multiple interrupt flags to indicate the specific source of the interrupt within the peripheral.

The NVIC provides:

- Up to 52 distinct interrupt sources (including internal and external interrupts)
- Eight priority levels
- A dedicated interrupt for each port

Real-Time Clock

A real-time clock (RTC) keeps the time of day in absolute seconds. The time base can be generated by connecting a 32kHz crystal between 32KIN and 32KOUT or an external clock source can be applied to the 32KIN pin. The external clock source must meet the electrical/timing requirements in the EC table. The 32kHz output can be directed to a GPIO for observation and use.

The 32-bit seconds register can count up to approximately 136 years and be translated to calendar format by application software. A time-of-day alarm and independent subsecond alarm can cause an interrupt or wake the device from stop mode.

The wake-up timer allows the device to remain in low power mode for extended periods of time. The minimum wake-up interval is 244µs.

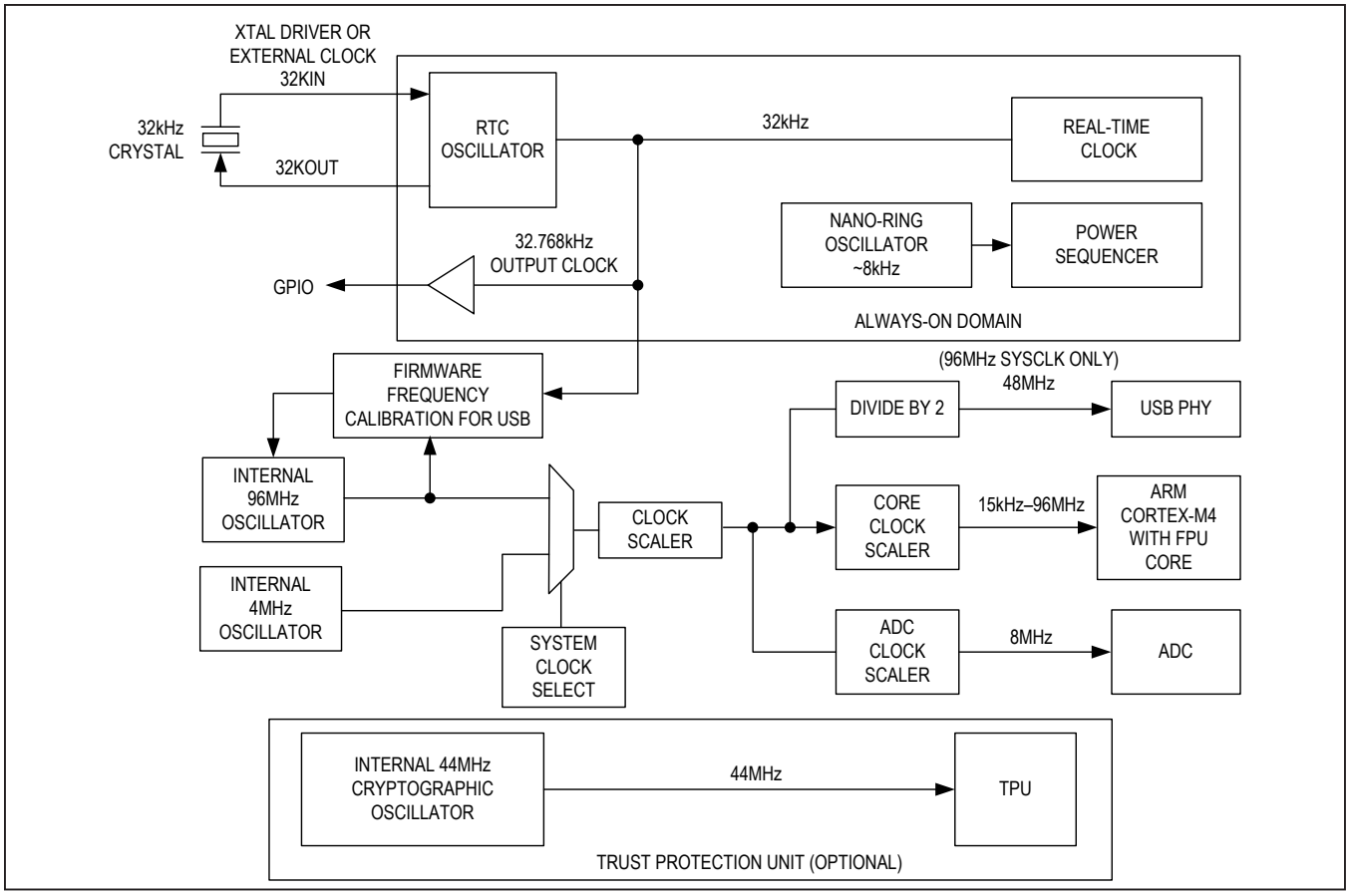


Figure 2. MAX32620/MAX32621 Clock Scheme (TPU on MAX32621 Only)

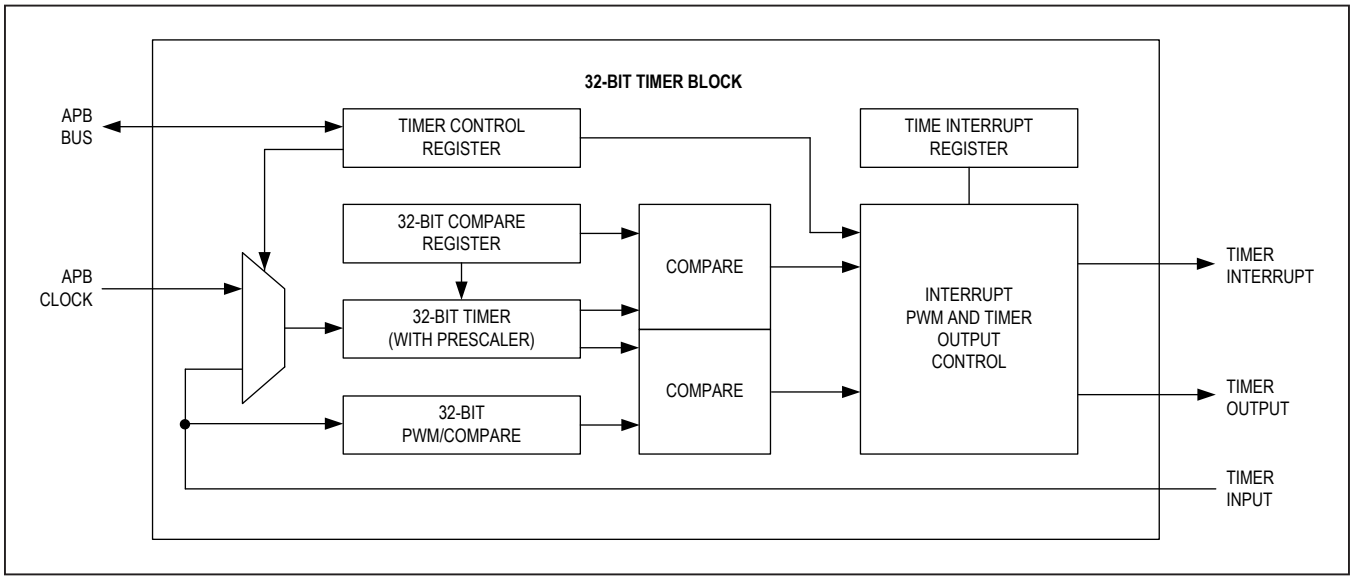


Figure 3. Timer Block Diagram, 32-Bit Mode

An external 32kHz crystal or clock source is required for USB operation, even if the RTC function is not used. Although the USB timing is derived from the internal 96MHz oscillator, the default accuracy is not sufficient for USB operation. Firmware trimming of the 96MHz oscillator using the 32kHz timebase as a reference is necessary to comply with USB timing requirements.

I²C Master and Slave Ports

The I²C interface is a bidirectional, 2-wire serial bus that provides a medium-speed communications network. It can operate as a one-to-one, one-to-many or many-to-many communications medium.

Three I²C interfaces allow for up to three I²C master engines and one I²C-selectable slave engine which interface to a wide variety of I²C-compatible peripherals. These engines support both Standard-mode and Fast-mode I²C standards. The slave engine shares the same I/O port as the master engines and is selectable through the I/O configuration settings. It provides the following features:

- Master or slave mode operation
- Supports standard (7-bit) or expanded (10-bit) addressing
- Support for clock stretching to allow slower slave devices to operate on higher speed busses
- Multiple transfer rates:
  - Standard-mode: 100kbps
  - Fast-mode: 400kbps
- Internal filter to reject noise spikes
- Receiver FIFO depth of 16 bytes
- Transmitter FIFO depth of 16 bytes

Serial Peripheral Interface—Master

The SPI master-mode-only (SPIM) interface operates independently in a single or multiple slave system and is fully accessible to the user application.

The SPI ports provide a highly configurable, flexible and efficient interface to communicate with a wide variety of SPI slave devices. The three SPI master ports (SPI0, SPI1, SPI2) support the following features:

- Supports all four SPI modes (0,1,2,3) for single-bit communication
- 3 or 4 wire mode for single-bit slave device communication
- Full-duplex operation in single-bit, 4-wire mode
- Dual and quad I/O supported
- Up to 5 slave select lines per port
- Up to 2 slave ready lines
- Programmable interface timing
- Programmable SCK frequency and duty cycle
- Programmable SCK alternate timing
- SS (slave select) assertion and deassertion timing with respect to leading/trailing SCK edge

Serial Peripheral Interface—Execute in Place (SPIX) Master

The SPIX allows the CPU to transparently execute instructions stored in an external SPI flash. Instructions fetched through the SPIX master are cached just like instructions fetched from internal program memory. The SPIX master can also be used to access large amounts of external static data that would otherwise reside in internal data memory.

Serial Peripheral Interface—Slave

The SPI slave (SPIS) port provides a highly configurable, flexible, and efficient interface to communicate with a wide variety of SPI master devices. The SPI slave interface provides the following features:

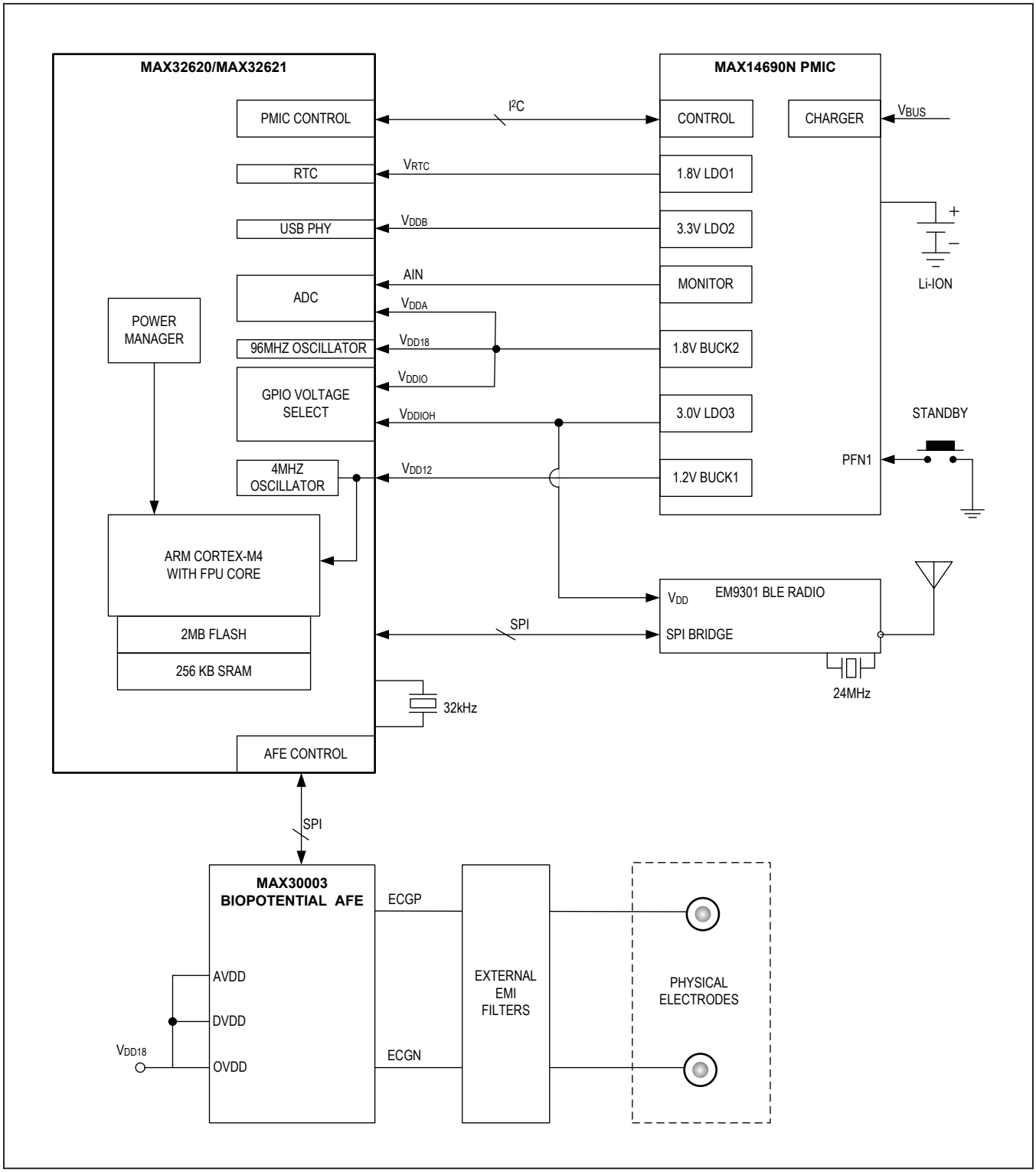
- Supports SPI modes 0 and 3
- Full-duplex operation in single-bit, 4-wire mode
- Slave select polarity fixed (active low)
- Dual and Quad I/O supported
- High-speed AHB access to transmit and receive using 32-byte FIFOs
- Four interrupts to monitor FIFO levels

UART

All four universal asynchronous receiver-transmitter (UART) interfaces support full-duplex asynchronous communication with optional hardware flow control (HFC) modes to prevent data overruns. If HFC mode is enabled on a given port, the system uses two extra pins to implement the industry-standard request to send (RTS) and clear to send (CTS) methodology. Each UART is individually programmable.

- 2-wire interface or 4-wire interface with flow control
- 2x 32-byte send/receive FIFOs, one for transmit and receive
- Full-duplex operation for asynchronous data transfers
- Programmable interrupt for receive and transmit
- Independent baud-rate generator
- Programmable 9th bit parity support
- Start/stop bit support
- Hardware flow control using RTS/CTS
- Maximum baud rate 1843.2kB

Typical Application Circuit—Wearable Cardiac Monitor



Ordering Information

PART	FLASH (MB)	SRAM (KB)	TRUST PROTECTION UNIT	PIN-PACKAGE
MAX32620ICQ+	2	256	No	100 TQFP
MAX32620IWG+	2	256	No	81 WLP
MAX32620IWG+T	2	256	No	81 WLP
MAX32620IWGL+*	1	256	No	81 WLP
MAX32620IWGL+T*	1	256	No	81 WLP
MAX32621ICQ+	2	256	Yes	100 TQFP
MAX32621IWG+	2	256	Yes	81 WLP
MAX32621IWG+T	2	256	Yes	81 WLP

+Denotes a lead(Pb)-free/RoHS-compliant package.

T = Tape and reel.

Package Information

For the latest package outline information and land patterns (footprints), go to **www.maximintegrated.com/packages**. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
81 WLP	W813D3+1	**21-0776**	Refer to **Application Note 1891**
100 TQFP-EP	C100E+3	**21-0116**	**90-0154**

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	6/15	Initial release	—
1	1/17	Added 4MHz clock option to EC table, added new GPIO V_{DDIO}/V_{DDIOH} option while supporting legacy V_{DD18} I/O supply to EC table, pin configuration, and pin description, absolute maximum rating for V_{RTC} changed from 3.6V to 1.89V, $V_{AIN(MIN)}$ typo corrected from V_{SS} to V_{SSA}, $\overline{RSTN}$ pin supply corrected from V_{DD18} to V_{RTC}, added I^2C and SPI timings, updated feature descriptions to conform to MAX32625/MAX32626 style, corrected Table 1 title, corrected part number in detailed description, added text in General Description describing differences between “C” and “A” revisions of the device, corrected RTC frequency to 32.768kHz, changed instances of WTD to WDT, corrected instances of T_A = +20°C to T_A = +25°C, changed page 1 typical values from current to power, updated I_{DDxx} typical values, removed redundant feature list on page 26, removed references to SPI bridge from I/O Matrix as the feature was never implemented, recommended V_{DD12} bypass capacitor changed from 100nF to 1.0µF, corrected ARM Cortex trademark usage in text and figures, IIH3V min/max from ±1 to ±2, $V_{RST(MIN)}$ from 1.62V to 1.61V, f_{INTCLK} min/max from 94.08/97.92 to 94/98MHz, corrected $f_{RCCLK(MIN)}$ from 3.9 to 0.001MHz to clarify effect of clock divider option, but no change to device, moved 1-Wire Master I/O to Table 1, added MAX32620IWGL+ and MAX32620IWGL+T part numbers	1–8, 10–16, 18–26

For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim Integrated’s website at www.maximintegrated.com.

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